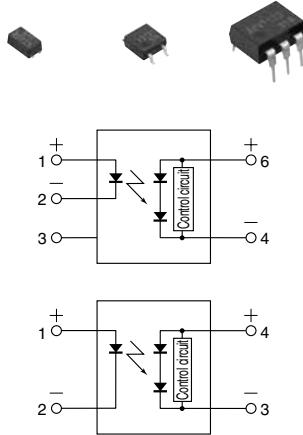


Photovoltaic MOSFET drivers of wide variation

Photovoltaic MOSFET Driver (APV1, 2)



FEATURES

1. High-speed switching

Since release time is typ. 0.1 ms, the MOSFET can be turned off quickly in a urgent situation.

2. Space saving

With a built-in control circuit, an external resistor is not needed. This contributes to making substrates more compact.

3. High insulation

DIP type: 5,000 V

SOP type: 2,500 V

SSOP type: 1,500 V

4. Extensive product lineup

Products include SSOP, SOP4-pin and DIP6-pin.

TYPICAL APPLICATIONS

- Power supply (Vcc) for electronic circuits
- Driving MOSFET

Compliance with RoHS Directive

TYPES

Output rating		Package	Part No.				Packing quantity		
Drop-out voltage (Typ.)	Short circuit current (Typ.)		Through hole terminal	Surface-mount terminal					
			Tube packing style	Tube packing style	Tape and reel packing style	Tube	Tape and reel		
8.7V	14µA	DIP6-pin	APV1122	APV1122A	APV1122AX	APV1122AZ	1 tube contains 50 pcs. 1 batch contains 500 pcs.	1,000 pcs.	
8.7V	14µA	SOP4-pin* ³	—	APV1121S	APV1121SX	APV1121SZ	1 tube contains 100 pcs. 1 batch contains 2,000 pcs.		
8.2V	8µA		—	APV2121S	APV2121SX	APV2121SZ	—	3,500 pcs.	
8.2V	8µA	SSOP* ⁴	—	—	APV2111VY	APV2111VW	—		

Notes: *1 SOP type is picked from 1/2-pin side, SSOP type is picked from 1/4-pin side.

*2 SOP type is picked from 3/4-pin side, SSOP type is picked from 2/3-pin side.

*3 For space reasons, the two initial letters of the part number "AP", package (SOP) indicator "S" and the packing style indicator "X" or "Z" are not marked on the relay. (Ex. the label for product number APV1121SX is V1121).

*4 Tape and reel package is the standard packing style.

For space reasons, the two initial letters of the part number "AP", package (SSOP) indicator "V" and the packing style are not marked on the relay. (Ex. the label for product number APV2111VY is V2111).

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item	Symbol	APV1122(A)	APV1121S	APV2121S	APV2111V	Remarks
Input	LED forward current	I _F		50mA		
	LED reverse voltage	V _R		5V		
	Peak forward current	I _{FP}		1A		f = 100 Hz, Duty Ratio = 0.1%
	Power dissipation	P _{in}		75mW		
I/O isolation voltage		V _{iso}	5,000V AC	2,500V AC	2,500V AC	1,500V AC
Temperature limits	Operating	T _{opr}	−40°C to +85°C −40°F to +185°F			Non-condensing at low temperatures
	Storage	T _{sig}	−40°C to +100°C −40°F to +212°F			

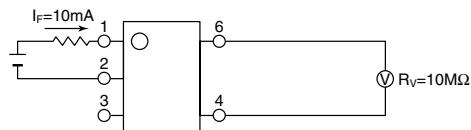
Photovoltaic MOSFET Driver

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

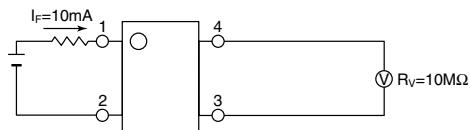
Item	Symbol	APV1122(A)	APV1121S	APV2121S	APV2111V	Condition
LED operate current	I_{Fon}	0.6mA		0.85mA		$V_{oc} = 5V$
Maximum		3mA				
LED turn off current	I_{Foff}		0.2mA			$V_{oc} = 1V$
Minimum		0.5mA		0.75mA		
LED dropout voltage	V_F		1.15V			$I_F = 10mA$
Maximum		1.5V				
Drop-out voltage*	V_{oc}	6V		5V		$I_F = 10mA$
Typical		8.7V		8.2V		
Short circuit current**	I_{sc}	5μA		3μA		$I_F = 10mA$
Minimum		14μA		8μA		
Turn on time***	T_{on}	0.4ms		0.8ms		$I_F = 10mA, C_L = 1,000pF$
Turn off time***	T_{off}		0.1ms			$I_F = 10mA, C_L = 1,000pF$
I/O capacitance	C_{iso}	0.8pF				$V_B = 0V, f = 1MHz$
Maximum		1.5pF				
Initial I/O isolation resistance	R_{iso}		1,000MΩ			500V DC

*Drop-out voltage measurement circuit

APV1122(A)

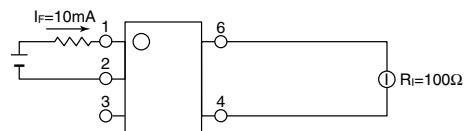


APV1121S, APV2121S, APV2111V

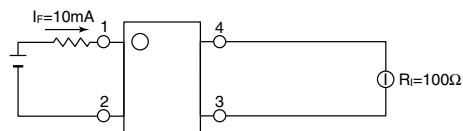


**Short circuit current measurement circuit

APV1122(A)

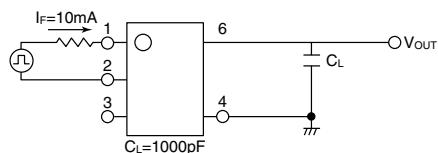


APV1121S, APV2121S, APV2111V

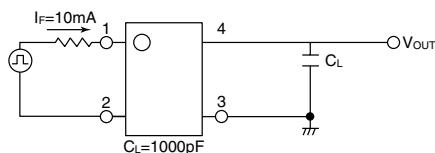


***Turn on/Turn off time measurement circuit

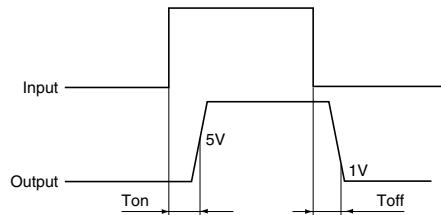
APV1122(A)



APV1121S, APV2121S, APV2111V



***Turn on time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

Item	Symbol	Recommended value	Unit
Input LED current	I_F	10	mA

■ For Dimensions

■ For Schematic and Wiring Diagrams

■ For Cautions for Use

■ These products are not designed for automotive use.

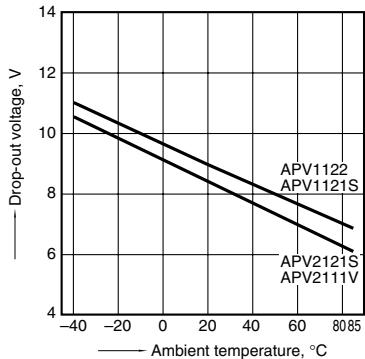
If you are considering to use these products for automotive applications, please contact your local Panasonic Electric Works technical representative.

For more information

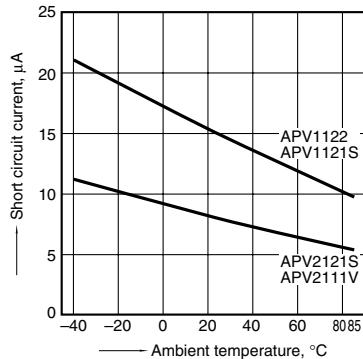
Photovoltaic MOSFET Driver

REFERENCE DATA

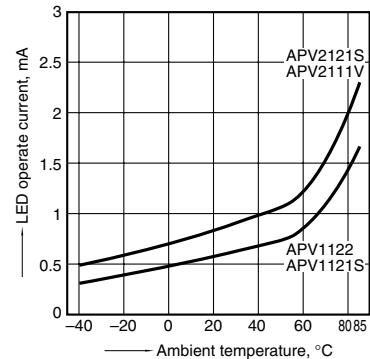
1. Drop-out voltage vs. ambient temperature characteristics
Input current: 10mA



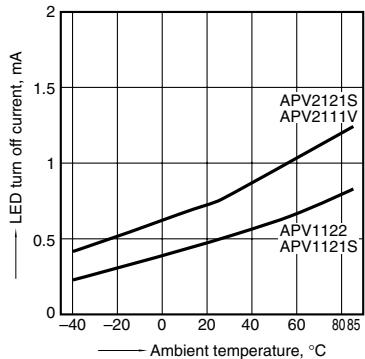
2. Short circuit current vs. ambient temperature characteristics
Input current: 10mA



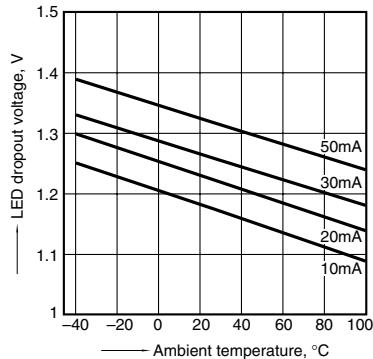
3. LED operate current vs. ambient temperature characteristics
Drop-out voltage: 5V



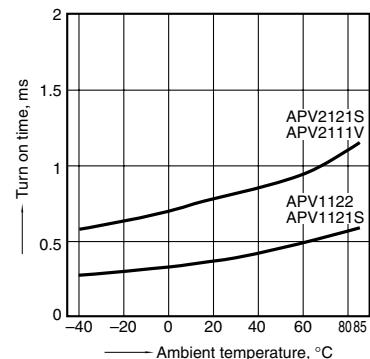
4. LED turn off current vs. ambient temperature characteristics
Drop-out voltage: 1V



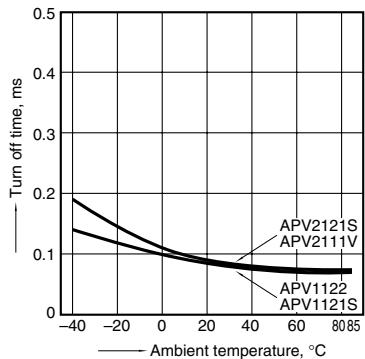
5. LED dropout voltage vs. ambient temperature characteristics
LED forward current: 5 to 50mA



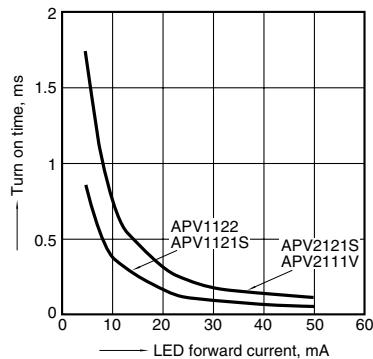
6. Turn on time vs. ambient temperature characteristics
LED forward current: 10mA
Load capacity: 1,000pF; output voltage: 5V



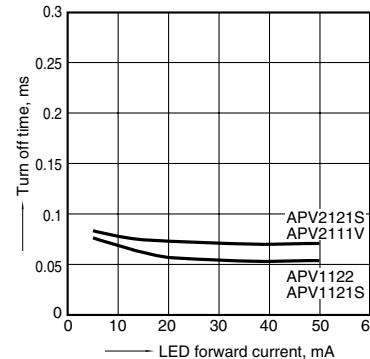
7. Turn off time vs. ambient temperature characteristics
LED forward current: 10mA
Load capacity: 1,000pF; output voltage: 1V



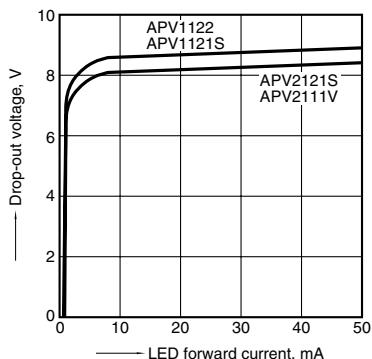
8. Turn on time vs. LED forward current characteristics
Load capacity: 1,000pF; output voltage: 5V



9. Turn off time vs. LED forward current characteristics
Load capacity: 1,000pF; output voltage: 1V



10. Drop-out voltage vs. LED forward current characteristics



11. Short circuit current vs. LED forward current characteristics

